

## Absolute Maximum Ratings

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/Distributors for availability and specifications.
Voltage at Any Pin
Operating Temperature
-0.3 V to $\mathrm{V}_{\mathrm{DD}}+0.3 \mathrm{~V}$
$0^{\circ} \mathrm{C}$ to $+70^{\circ} \mathrm{C}$
Storage Temperature
Electrical Characteristics
$\mathrm{T}_{\mathrm{A}}$ within operating temperature range, $\mathrm{V}_{\mathrm{SS}}=\mathrm{GND}, 3 \mathrm{~V} \leq \mathrm{V}_{\mathrm{DD}} \leq 15 \mathrm{~V}$ unless otherwise specified.

| Parameter | Conditions | Min | Typ | Max | Units |
| :---: | :---: | :---: | :---: | :---: | :---: |
| Quiescent Current Drain | $\mathrm{V}_{\mathrm{DD}}=15 \mathrm{~V}$ |  |  | 10 | $\mu \mathrm{A}$ |
| Operating Current Drain | $\mathrm{V}_{\mathrm{DD}}=10 \mathrm{~V}, \mathrm{f}_{\mathrm{IN}}=4.19 \mathrm{MHz}$ |  | 1.2 | 2.5 | mA |
| Frequency of Oscillation | $\begin{aligned} & V_{D D}=10 \mathrm{~V} \\ & V_{D D}=6 \mathrm{~V} \end{aligned}$ | $\begin{aligned} & \text { DC } \\ & \text { DC } \end{aligned}$ |  | $\begin{gathered} 4.5 \\ 2 \\ \hline \end{gathered}$ | $\begin{aligned} & \mathrm{MHz} \\ & \mathrm{MHz} \end{aligned}$ |
| Output Current Levels <br> Logical "1" Source <br> Logical "0" Sink | $\begin{aligned} & V_{D D}=10 V \\ & V_{O}=5 V \end{aligned}$ | $\begin{aligned} & 500 \\ & 500 \end{aligned}$ |  |  | $\mu \mathrm{A}$ <br> $\mu \mathrm{A}$ |
| Output Voltage Levels <br> Logical " 1 " <br> Logical "0" | $\begin{aligned} & V_{D D}=10 V \\ & I_{O}=10 \mu \mathrm{~A} \end{aligned}$ | 9.0 |  | 1.0 | $\begin{aligned} & \mathrm{V} \\ & \mathrm{~V} \end{aligned}$ |

Note: For 3.58 MHz operation, $\mathrm{V}_{\mathrm{DD}}$ must be $\geq 10 \mathrm{~V}$.

## Functional Description

A connection diagram for the MM5369 is shown in Figure 1 and a block diagram is shown in Figure 2.

## TIME BASE

A precision time base is provided by the interconnection of a $3,579,545 \mathrm{~Hz}$ quartz crystal and the RC network shown in Figure 3 together with the CMOS inverter/amplifier provided between the OSC IN and the OSC OUT terminals. Resistor R1 is necessary to bias the inverter for class A amplifier operation. Capacitors C1 and C2 in series provide the parallel load capacitance required for precise tuning of the quartz crystal.
The network shown provides > 100 ppm tuning range when used with standard crystals trimmed for $\mathrm{C}_{\mathrm{L}}=12 \mathrm{pF}$. Tuning to better than $\pm 2 \mathrm{ppm}$ is easily obtainable.

| Package Dissipation | 500 mW |
| :--- | ---: |
| Maximum VCC Voltage | 16 V |
| Operating VCC Range | 3 V to 15 V |
| Lead Temperature (Soldering, 10 seconds) | $300^{\circ} \mathrm{C}$ |

## Functional Description (Continued)


*To be selected based on xtal used
FIGURE 3. Crystal Oscillator Network


FIGURE 4. Plot of Divide-By vs Duty Cycle



FIGURE 5. Typical Current Drain vs Oscillator Frequency


Physical Dimensions inches (millimeters) unless otherwise noted


Physical Dimensions inches (millimeters) unless otherwise noted (Continued)


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